

T6400 SERIES

BIDIRECTIONAL TRIODE THYRISTORS

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Repetitive peak off-stage voltage, gate open			
(T _J = -65 to +110°C) T6400B T6400D T6400M	V_{DRM}	200 400 600	Volts
T6400N		800	
RMS on-state current (conduction angle = 360° , $T_c \le 70^{\circ}C$)	I _{T(RMS)}	40	Amps
Peak non-repetitive surge current (One Cycle, 60Hz)	I _{TSM}	300	Amps
Circuit fusing considerations (T _J = -65 to +110°C, t = 1.25 to 10ms)	l ² t	450	A ² s
Peak gate power (pulse width = 10μ s)	P _{GM}	40	Watts
Average gate power	P _{G(AV)}	0.75	Watts
Peak gate current (pulse width ≤ 10μs)	I _{GM}	12	Amps
Operating junction temperature range	Tı	-65 to +110	°C
Storage temperature range	T _{stg}	-65 to +150	°C
Stud torque		30	In. lb.

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal resistance, junction to case	R _{eJC}	0.8	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C and either polarity of MT2 to MT1 voltage, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak off state current					mA
$(V_D = V_{DRM}, \text{ gate open, } T_J = 110^{\circ}\text{C})$	I _{DRM}	-	-	4	IIIA
Peak on-state voltage (either direction)	V				Volts
(I _{TM} = 100A peak)	V _{TM}	V _{TM} -	1.5	2.0	Volts
DC gate trigger current (continuous dc)					
$(V_D = 12V, R_L = 30\Omega)$					
MT2(+), G(+)		-	15	50	
MT2(+), G(-)	I _{GT}	-	30	80	mA
MT2(-), G(-)	IG1	-	20	50	IIIA
MT2(-), G(+)		-	40	80	
$MT2(+)$, $G(+)$; $MT2(-)$, $G(-)$, $T_C = -65$ °C		-	-	125	
MT2(+), G(-); MT2(-), G(+), $T_c = -65$ °C		-	-	240	
DC gate trigger voltage (continuous dc), all trigger modes					
$(V_D = 12V, R_L = 30\Omega)$	V _{GT}	-	1.35	2.5	Volts
$(V_D = 12V, R_L = 30\Omega, T_C = -65^{\circ}C)$	∨ GT	-	-	3.4	VUILS
$(V_D = Rated V_{DRM}, R_L = 125\Omega, T_C = 110^{\circ}C)$		0.2	-	-	



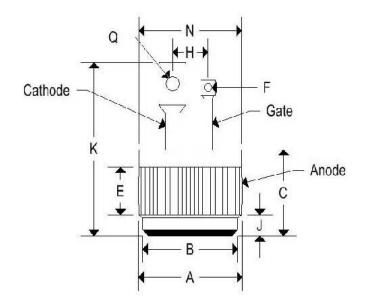
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Holding current (either direction)					
$(V_D = 12V, gate open, I_T = 500mA, T_C = 25^{\circ}C)$	I _H	-	25	60	mA
$(V_D = 12V, gate open, I_T = 500mA, T_C = -65^{\circ}C)$		-	-	100	
Gate controlled turn on time	+				116
$(V_D = Rated V_{DRM}, I_T = 60A, I_{GT} = 200mA, rise time = 0.1 \mu s)$	Lgt	-	1.7	3	μs
Critical rate of rise of commutating voltage					
(commutating di/dt = 22A/ms, gate unenergized, V_D = Rated V_{DRM} , $I_{T(RMS)}$ = 40A,	dv/dt(c)		5		V/µs
$T_C = 70^{\circ}C$			3	-	

MECHANICAL CHARACTERISTICS

Case	Digi PF1
Marking	Alpha-numeric

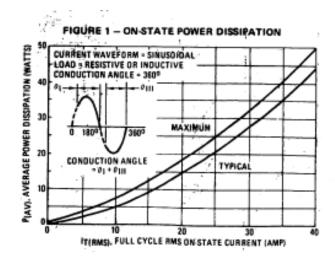


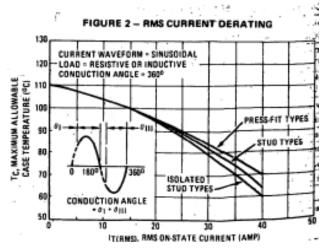
	DIGI PF1				
	Inc	hes	Millin	neters	
	Min	Max	Min	Max	
Α	0.501	0.505	12.730	12.830	
F	32.	0.160	35.	4.060	
G	0.085	0.095	2.160	2.410	
Н	0.060	0.070	1.520	1.780	
J	0.300	0.350	7.620	8.890	
K	12	1.050	12	26.670	
L	(4)	0.670	(=)	17,020	
Q	0.055	0.085	1.400	2.160	



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